PATENT APPLICATION TRANSMITTAL LETTER

(Large Entity)

Docket No. G0186

TO THE ASSISTANT COMMISSIONER FOR PATENTS

Transmitted herewith for filing under 35 U.S.C. 111 and 37 C.F.R. 1.53 is the patent application of:

Zhigang Wang, Yue-Song He & Richard Fastow

For: TWO-STEP SOURCE SIDE IMPLANT FOR IMPROVING SOURCE RESISTANCE AND SHORT CHANNEL

EFFECT IN DEEP SUB-0.18um FLASH MEMORY TECHNOLOGY

Enclosed are:						
X	Certificate of Mailing with Express Mail Mailing Label No. EK619297984US					
	Six (6) sheets of dra	awings.				
	A certified copy of a	application.				
X	Declaration 🗷 Signed.	☐ Unsigned.				
X	Power of Attorney					
	Information Disclosure Statement					

Preliminary Amendment

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Other: Assignment & PTO/SB/35

CLAIMS A	AS FILED
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For	#Filed	#Allowed	#Extra		Rate	Fee
Lotal Claims	7	- 20 =	0	x	\$18.00	\$0.00
Indep. Claims	2	- 3 =	0	×	\$84.00	\$0.00
Multiple Dependen	t Claims (check	if applicable)		-		\$0.00
			<u></u>		BASIC FEE	\$740.00
					TOTAL FILING FEE	\$740.00

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to cover the filing fee is enclosed.

▼ The Commissioner is hereby authorized to charge and credit Deposit Account No.

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as described below. A duplicate copy of this sheet is enclosed.

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☐ Charge the issue fee set in 37 C.F.R. 1.18 at the mailing of the Notice of Allowance,

pursuant to 37 C.F.R. 1.311(b).

Dated: 1/18/02

H. Donald Nelson, Reg. No. 28,980

cc:

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REQUEST AND CERTIFICATION UNDER 35 U.S.C. 122(b)(2)(B)(i)

First Named Inventor Zhigang Wang

Title TWO-STEP SOURCE SIDE IMPLANT FOR

Atty Docket Number

G0186

IMPROVING SOURCE RESISTANCE AND ...

I hereby certify that the invention disclosed in the attached application has not and will not be the subject of an application filed in another country, or under a multilateral agreement, that requires publication at eighteen months after filing. I hereby request that the attached application not be published under 35 U.S.C. 122(b).

1/18/02

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Date

Willonald Melson Signature

H. Donald Nelson

Typed or printed name

This request must be signed in compliance with 37 CFR 1.33(b) and submitted with the application **upon filing.**

Applicant may rescind this nonpublication request at any time. If applicant rescinds a request that an application not be published under 35 U.S.C. 122(b), the application will be scheduled for publication at eighteen months from the earliest claimed filing date for which a benefit is claimed.

If applicant subsequently files an application directed to the invention disclosed in the attached application in another country, or under a multilateral international agreement, that requires publication of applications eighteen months after filing, the applicant must notify the United States Patent and Trademark Office of such filing within forty-five (45) days after the date of the filing of such foreign or international application. Failure to do so will result in abandonment of this application (35 U.S.C. 122(b)(2)(B)(iii)).

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Burden Hour Statement: This collection of information is required by 37 CFR 1.213(a). The information is used by the public to request that an application not be published under 35 U.S.C. 122(b) (and the PTO to process that request). Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This form is to take 6 minutes to complete. This time will vary depending upon the needs of the individual case. Any comments on the amount of time you are required to complete this form should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, Washington, DC 20231. DO NOT SEND FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Assistant Commissioner for Patents, Washington, DC 20231.

CERTIFICATE OF MAILING BY "EXPRESS MAIL" (37 CFR 1.10) Docket No.								
Applicant(s): Zhigang Wang et al. G0186								
Serial No. not yet assigned		Group Art Unit not yet assigned						
not yet assigned Invention: TWO-STEP SOURCE SIDE IMPLANT FOR IMPROVING SOURCE RESISTANCE AND SHORT CHANNEL EFFECT IN DEEP SUB-0.18um FLASH MEMORY TECHNOLOGY								
I hereby certify that the following correspondence:								
Patent Application								
Similar de la constant de la constan	(Identify type	of correspondence)						
내 실 37 CFR 1.10 in an en [] 1/18/								
		H. Donald						
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